Taiwan Semiconductor

# 8A, 50V - 600V Super Fast Rectifier

### FEATURES

- AEC-Q101 qualified available
- Glass passivated chip junction
- High efficiency, Low V<sub>F</sub>
- High current capability
- High reliability
- High surge current capability
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

### **APPLICATIONS**

- DC to DC converter
- Switching mode converters and inverters
- Freewheeling application

## **MECHANICAL DATA**

- Case: ITO-220AC
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.70g (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
١ <sub>F</sub>	8	А	
V <sub>RRM</sub>	50 - 600	V	
I <sub>FSM</sub>	125	А	
T <sub>J MAX</sub>	150	°C	
Package	ITO-220AC		
Configuration	Single	die	





PIN 2 O-

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)										
PARAMETER	SYMBOL	SFAF 801G	SFAF 802G	SFAF 803G	SFAF 804G	SFAF 805G	SFAF 806G	SFAF 807g	SFAF 808G	UNIT
Marking code on the device		SFAF 801G	SFAF 802G	SFAF 803G	SFAF 804G	SFAF 805G	SFAF 806G	SFAF 807G	SFAF 808G	
Repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	300	400	500	600	V
Reverse voltage total rms value	V <sub>R(RMS)</sub>	35	70	105	140	210	280	350	420	V
Forward current	١ <sub>F</sub>		8					А		
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I <sub>FSM</sub>		125					A		
Junction temperature	TJ		-55 to +150				°C			
Storage temperature	T <sub>STG</sub>	-55 to +150				°C				



THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ТҮР	UNIT	
Junction-to-case resistance	R <sub>eJC</sub>	4	°C/W	

PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
SFAF80 SFAF80 SFAF80 SFAF80				-	0.950	V
Forward voltage <sup>(1)</sup>	SFAF805G SFAF806G	- I <sub>F</sub> = 8A, T <sub>J</sub> = 25°C -	V <sub>F</sub>	-	1.300	V
	SFAF807G SFAF808G			-	1.700	V
Reverse current @ rated $V_R^{(2)}$		$T_J = 25^{\circ}C$	I <sub>R</sub>	-	10	μA
		T <sub>J</sub> = 100°C		-	400	μA
lunction conscitance	SFAF801G SFAF802G SFAF803G SFAF804G		C	90	-	pF
Junction capacitance	SFAF805G SFAF806G SFAF807G SFAF808G	1MHz, V <sub>R</sub> = 4.0V	CJ	60	-	pF
Reverse recovery time		IF = 0.5A, IR = 1.0A Irr = 0.25A	t <sub>rr</sub>	-	35	ns

#### Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION			
ORDERING CODE <sup>(1)(2)</sup>	PACKAGE	PACKING	
SFAF8xG	ITO-220AC	50 / Tube	
SFAF8xGH	ITO-220AC	50 / Tube	

Notes:

1. "x" defines voltage from 50V(SFAF801G) to 600V(SFAF808G)

2. "H" means AEC-Q101 qualified



### **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)

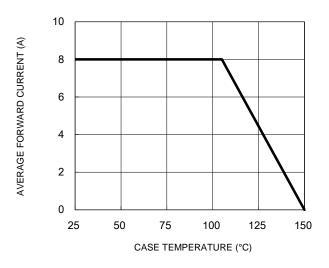
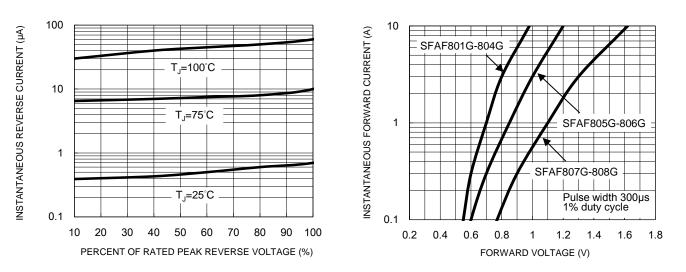


Fig.1 Forward Current Derating Curve

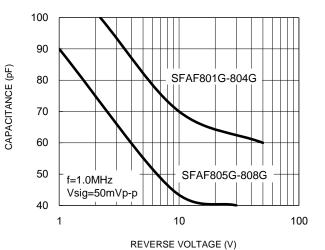
#### **Fig.3 Typical Reverse Characteristics**





## Fig.5 Maximum Non-Repetitive Forward Surge Current

**Fig.4 Typical Forward Characteristics** 

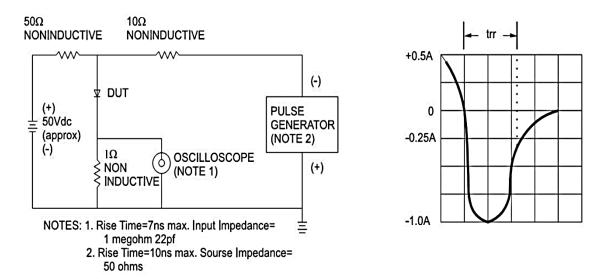


**Fig.2 Typical Junction Capacitance** 



## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 



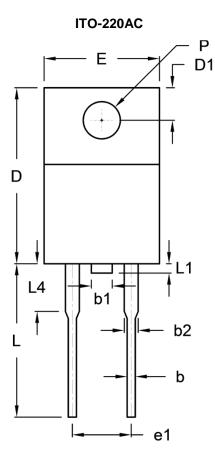
#### Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram

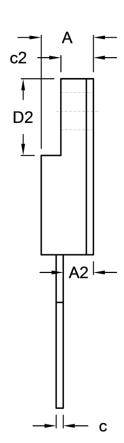


# SFAF801G - SFAF808G

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## PACKAGE OUTLINE DIMENSIONS





DIM. Unit		(mm)	Unit (	inch)	
	Min.	Min. Max.		Max.	
A	4.30	4.70	0.169	0.185	
A2	2.30	2.90	0.091	0.114	
b	0.50	0.90	0.020	0.035	
b1	-	1.80	-	0.071	
b2	0.95	1.45	0.037	0.057	
с	0.46	0.76	0.018	0.030	
c2	2.50	3.10	0.098	0.114	
D	14.80	15.50	0.583	0.610	
D1	2.40	3.20	0.094	0.126	
D2	6.30	6.90	0.248	0.272	
Е	9.60	10.30	0.378	0.406	
e1	4.95	5.20	0.195	0.205	
L	12.60	13.80	0.496	0.543	
L1	0.00	1.60	0.000	0.063	
L4	-	4.10	-	0.161	
Р	3.00	3.40	0.118	0.134	

### **MARKING DIAGRAM**



P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



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